

**IN THE CLAIMS**

Please amend claims 1, 3, 7, 8, 13, 14, 15, 27, 28 as follows:

1. (Currently Amended) A method for signal-conditioning utilizing a signal-conditioning circuit, said method comprising the steps of:

applying an offset correction voltage to a noninverting input of an amplifier of said signal-conditioning circuit; and

applying a magnetoresistor half-bridge signal to an inverting input of said amplifier of said signal-conditioning circuit, wherein said offset correction voltage at said noninverting input drives compensates to drive an output voltage of said signal-conditioning circuit to an input voltage, which is divided by a value of two, thereby generating a resulting voltage value, which is utilized to automatically calibrate said magnetoresistive half-bridge signal for temperature compensation purposes by calibration for temperature compensation thereof by said signal-conditioning circuit.

2. (Original) The method of claim 1 further comprising the step of:

configuring said signal-conditioning circuit to comprise an InSb signal-conditioning circuit.

3. (Previously Amended) The method of claim 1 further comprising the step of:

configuring said signal-conditioning circuit as a circuit comprising:

a noninverting signal input for application of offset correction voltages;

an inverting input for application of magnetoresistor half bridge signals for temperature compensation thereof.

4. (Previously Amended) The method of claim 1 further comprising the step of:

generating said magnetoresistor half-bridge signal utilizing at least one magnetoresistor.

5. (Previously Amended) The method of claim 1 further comprising the step of:

generating said magnetoresistor half-bridge signal utilizing a plurality of magnetoresistors.

6. (Previously Amended) The method of claim 1 further comprising the step of:

connecting at least two magnetoresistors to one another at a first node and at least two other magnetoresistors to one another at a second node, wherein said second node is connected to a positive input of said amplifier of said signal-conditioning circuit.

7. (Currently Amended) The method of claim 1 further comprising the step of:

coupling a first magnetoresistor coupled to a second magnetoresistor at a first node, wherein said first magnetoresistor is coupled to a supply voltage and said second magnetoresistor is coupled to a ground.

8. (Currently Amended) The method of claim 7 further comprising the step of:

coupling comprise a first resistor coupled to a second resistor at a second node, wherein said first resistor is coupled to said supply voltage and said second

resistor is coupled to said ground, such that said second node is coupled to a positive input of said amplifier.

9. (Original) The method of claim 8 further comprising the step of:

configuring said signal-conditioning circuit to comprise a third resistor coupled to said first node and to a third node, wherein said third node is connected to a negative input of said amplifier.

10. (Original) The method of claim 9 further comprising the step of:

configuring said signal-conditioning circuit to comprise a fourth resistor coupled to said third node and to an output of said amplifier.

11. (Previously Amended) The method of claim 1 further comprising the step of:

configuring said signal-conditioning circuit to comprise at least one magnetoresistor in series with at least one resistor connected to an inverting input of an amplifier of said signal-conditioning circuit;

wherein said at least one magnetoresistor comprises an InSb magnetoresistor that exhibits a negative scale factor temperature coefficient; and

wherein at least one magnet of said signal-conditioning circuit exhibits a negative scale factor temperature coefficient to thereby permit a gain of said amplifier to increase.

12. (Previously Amended) The method of claim 11 further comprising the step of:

configuring said at least one resistor to comprise a fixed temperature coefficient resistor.

13. (Currently Amended) The method of claim 12 further comprising the step of:

choosing said fixed low temperature coefficient resistor in series with said at least one magnetoresistor to thereby obtain a flat resultant temperature coefficient thereof dependent upon said fixed low temperature coefficient resistor.

14. (Currently Amended) A method for signal-conditioning utilizing a signal-conditioning circuit, said method comprising the step of:

applying an offset correction voltage to a noninverting input of a signal-conditioning circuit;

applying a magnetoresistor half-bridge signal to an inverting input of said signal-conditioning circuit, wherein said offset correction voltage at said noninverting input drives compensates to drive an output voltage of said signal-conditioning circuit to an input voltage, which is divided by a value of two, thereby generating a resulting voltage value, which is utilized to automatically calibrate said magnetoresistive half-bridge signal for temperature compensation purposes for temperature compensation thereof by said signal-conditioning circuit;

configuring said signal-conditioning circuit to comprise at least one magnetoresistor in series with at least one resistor located in an inverting input of an amplifier associated with said signal-conditioning circuit;

wherein said at least one magnetoresistor exhibits a negative scale factor temperature coefficient; and

wherein an associated magnet exhibits a negative scale factor temperature coefficient to thereby permit a gain of said amplifier to increase with temperature.

15. (Currently Amended) A system for signal-conditioning utilizing a signal-conditioning circuit, said system comprising:

an offset correction voltage applied to a noninverting input of a signal-conditioning circuit;

a magnetoresistor half-bridge signal applied to an inverting input of said signal-conditioning circuit, wherein said offset correction voltage at said non-inverting input drives compensates to drive an output voltage of said signal-conditioning circuit to an input voltage, which is divided by a value of two, thereby generating a resulting voltage value, which is utilized to automatically calibrate said magnetoresistive half-bridge signal for temperature compensation purposes by calibration for temperature compensation thereof by said signal condition circuit.

16. (Original) The system of claim 15 wherein said signal-conditioning circuit comprises an InSb signal-conditioning circuit.

17. (Previously Amended) The system of claim 15 wherein said signal-conditioning circuit comprises:

a noninverting signal input for application of offset correction voltages;

an inverting input for application of magnetoresistor half bridge signals for temperature compensation thereof.

18. (Previously Amended) The system of claim 15 wherein said magnetoresistor half-bridge signal is generated utilizing at least one magnetoresistor configured within said signal-conditioning circuit.

19. (Original) The system of claim 15 wherein said magnetoresistor half-bridge signal is generated utilizing a plurality of magnetoresistors configured within said signal-conditioning circuit.

20. (Previously Amended) The system of claim 15 wherein at least two magnetoresistors are connected to one another at a first node and at least two other magnetoresistors to one another at a second node, wherein said second node is connected to a positive input of said amplifier of said signal-conditioning circuit.

21. (Original) The system of claim 15 wherein said signal-conditioning circuit comprises a first magnetoresistor coupled to a second magnetoresistor at a first node, wherein said first magnetoresistor is coupled to a supply voltage and said second magnetoresistor is coupled to a ground.

22. (Original) The system of claim 21 wherein said signal-conditioning circuit comprises a first resistor coupled to a second resistor at a second node, wherein said first resistor is coupled to said supply voltage and said second resistor is coupled to said ground, such that said second node is coupled to a positive input of said amplifier.

23. (Original) The method of claim 22 wherein said signal-conditioning circuit comprises a third resistor coupled to said first node and to a third node, wherein said third node is connected to a negative input of said amplifier.

24. (Original) The system of claim 23 wherein said signal-conditioning circuit comprises a fourth resistor coupled to said third node and to an output of said amplifier.

25. (Original) The system of claim 15 wherein:

said signal-conditioning circuit comprises at least one magnetoresistor in series with at least one resistor located in an inverting input of an amplifier associated with said signal-conditioning circuit;

wherein said at least one magnetoresistor comprises an InSb that exhibits a negative scale factor temperature coefficient; and

wherein an associated magnet exhibits a negative scale factor temperature coefficient to thereby permit a gain of said amplifier to increase with temperature.

26. (Original) The system of claim 25 wherein said at least one resistor comprises a fixed temperature coefficient resistor.

27. (Currently Amended) The system of claim 26 wherein said fixed low temperature coefficient resistor is chosen in series with said at least one magnetoresistor to thereby obtain a flat resultant scale factor temperature coefficient thereof dependent upon said fixed low temperature coefficient resistor.

28. (Currently Amended) A system for signal-conditioning utilizing a signal-conditioning circuit, said system comprising:

an offset correction voltage applied to a noninverting input of a signal-conditioning circuit;

a magnetoresistor half-bridge signal applied to an inverting input of said signal-conditioning circuit;

a voltage electronically compensated at said noninverting input, wherein a resulting compensated voltage drives to drive an output voltage of said signal-conditioning circuit to an input voltage that is divided by a value of two during a calibration thereof;

wherein said signal-conditioning circuit is configured to comprise at least one magnetoresistor in series with at least one resistor connected to an inverting input of an amplifier of said signal-conditioning circuit;

wherein said at least one magnetoresistor exhibits a negative scale factor temperature coefficient; and

wherein at least one magnet of said signal-conditioning circuit exhibits a negative scale factor temperature coefficient to thereby permit a gain of said amplifier to increase with temperature.

29. (Previously Cancelled)